

2048K (256K x 8) CMOS ROM

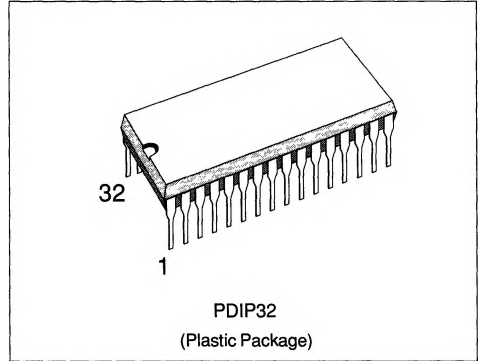
- VERY FAST ACCESS TIME : 120 ns
(Chip select or address access time)
- LOW POWER "CMOS" CONSUMPTION :
 - Operating current 50 mA Max.
 - Stand by current 20 μ A Max.
- SINGLE +5V \pm 10 % POWER SUPPLY.
- STATIC OPERATION.
- INPUTS AND OUTPUTS TTL COMPATIBLE.
- THREE STATE OUTPUTS.
- MASK PROGRAMMABLE ACTIVE LOW/HIGH CE.
- AUTOMATIC POWER DOWN.

DESCRIPTION

The M23C2001 is a 2,097,152 CMOS Masked Read Only Memory (ROM), organized as 262,144 x 8 bits. It is manufactured in 0.8 micron CMOS technology : Very fast access time of 120 ns makes it ideal for EPROM replacement on high performance, high volume running applications. Chip select line (CE) is active low or active high by mask programming, as per user's choice. When not active, it brings the device in stand by mode, suitable on battery operated systems. Output Enable is to be used for Outputs control. After 50 ns without input change, the M23C2001 automatically goes in power-down (Icc1 = 1 mA), the data remaining latched on the outputs.

PIN NAMES

A0-A17	Address Inputs
O0-O7	Data Outputs
$\overline{\text{CE}}$ /CE	Chip Enable Input
$\overline{\text{OE}}$	Output Enable
Vcc	+ 5V Power Supply
GND	Ground
NC	Not Connected

ADVANCE DATA

PIN CONNECTION
